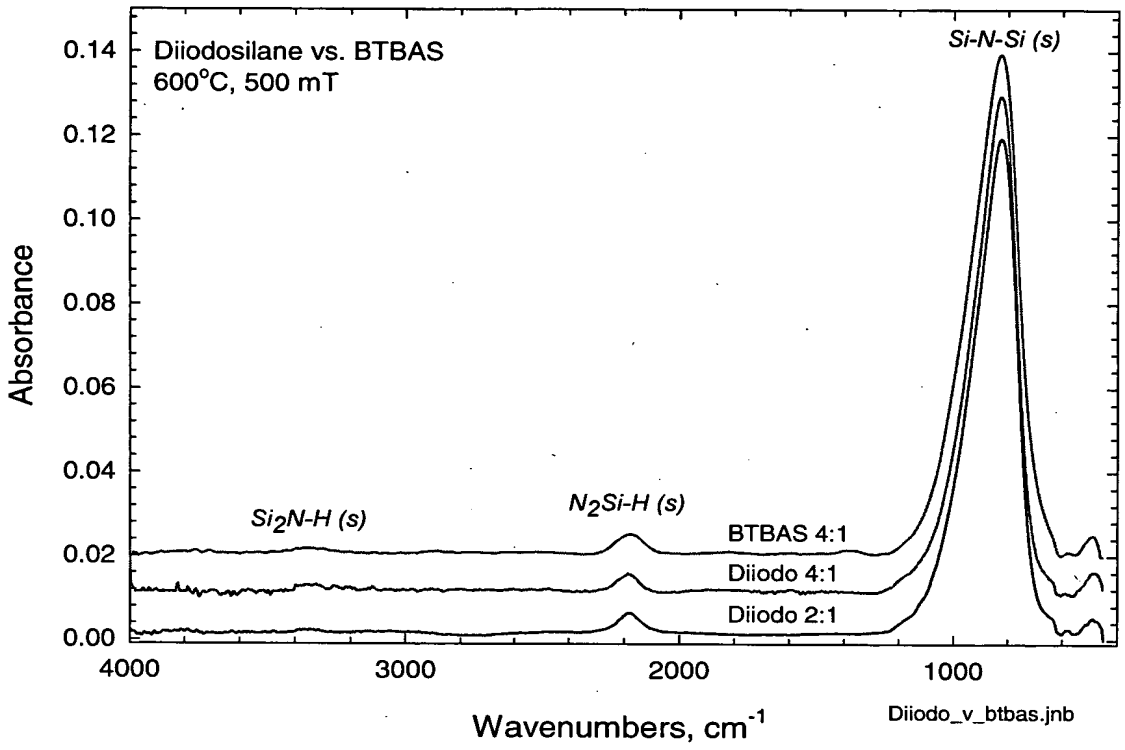
Diiodosilane vs. BTBAS
600°C, 500 mT
Si-N-Si (s)
Si2N-H (s)
N2Si-H (s)
BTBAS 4:1
Diiodo 4:1
Diiodo 2:1
Absorbance
0.14
0.12
0.10
0.08
0.06
0.04
0.02
0.00
4000
3000
2000
1000
Wavenumbers, cm-1
Diiodo_v_btbas.jnb

FIGURE 1